



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL10A475KA8NQNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 4.7 µF, 25V, ±10%, X5R, 0603

A. Samsung Part Number

<u>CL</u> <u>10</u> <u>A</u> <u>475</u> <u>K</u> <u>A</u> <u>8</u> <u>N</u> <u>Q</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

① S	Series	Samsung Multi-layer Ceramic Capacitor								
② S	Size	0603	(inch code)	L: 1.6	± 0.15	mm	W:	8.0	± 0.15	mm
3 D	Dielectric	X5R		8	Inner el	ectrode		Ni		
4 C	Capacitance	4.7	μF		Termina	ation		Cu		
⑤ C	Capacitance	±10	%		Plating			Sn 10	0%	(Pb Free)
to	olerance			9	Product	t		0603	Size dim	nension spec
6 R	Rated Voltage	25	V	10	Special		Reserved for future use			
⑦ TI	hickness	0.8	± 0.15 mm	(1)	Packagi	ing		Cardb	oard Ty	pe, 7" reel

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms					
Tan δ (DF)	0.1 max.						
Insulation	10,000Mohm or 100Mohm⋅μF	Rated Voltage 60~120 sec.					
Resistance	Whichever is Smaller						
Appearance	No abnormal exterior appearance	Microscope (×10)					
Withstanding	No dielectric breakdown or	250% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	X5R						
Characterisitcs	(From -55℃ to 85℃, Capacitance change shoud be within ±15%)						
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change : within ±12.5%	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5℃, 3±0.3sec.					
		(preheating : 80~120 ℃ for 10~30sec.)					
Resistance to	Capacitance change : within ±7.5%	Solder pot : 270±5℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance	Test condition				
Vibration Test	Capacitance change : within ±5%	Amplitude : 1.5mm				
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)				
		2hours × 3 direction (x, y, z)				
Moisture	Capacitance change: within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.2 max	40±2℃, 90~95%RH, 500+12/-0hrs				
	IR : 12.5‰·μF or Over					
		1000/				
High Temperature	Capacitance change: within ±12.5%	With 100% of the rated voltage				
Resistance	Tan δ : 0.2 max	Max. operating temperature				
	IR: 25MΩ·μF or Over					
		1000+48/-0hrs				
Temperature	Capacitance change: within ±7.5%	1 cycle condition				
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25°C				
		→ Max. operating temperature → 25°C				
		5 cycle test				

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C , 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.